NSN 5961-00-888-5458

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View Online at https://aerobasegroup.com/nsn/5961-00-888-5458 **Inclosure Material:** Glass and metal **Overall Length:** 0.210 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.210 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 breakdown voltage, collector-to-base, emitter open and -50.0 breakdown voltage, collector-to-emitter, base open and -50.0 breakdown voltage, emitter-to-base, collector open **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 10001-2635054 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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